

EM-0712

Shipped in packet-tape reel(5000pcs/Reel)

EM-0712 is ultra-small Hall effect ICs of a single silicon chip composed of Hall element and a signal processing IC.

Bipolar Hall Effect Latch Supply Voltage 1.6~5.5V

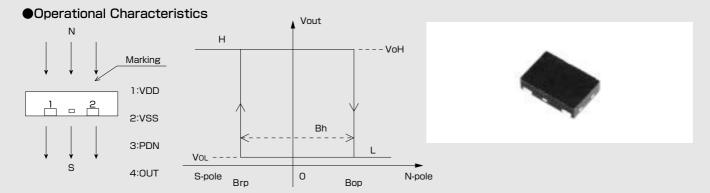
Power down Function

Ultra High Sensitivity Bop:1.8mT

Output **CMOS**

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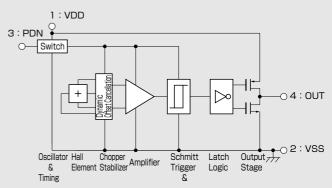
Notice: It is requested to read and accept "IMPORTANT NOTICE" written on the back of the front cover of this catalogue.



Magnetic flux density ●Absolute Maximum Ratings (Ta=25°C)

| Item | Symbol | Limit | Unit |
|-----------------------------|-----------------|-------------------------|------|
| Supply Voltage | VDD | −0.1 ~ 6.0 | V |
| PDN input voltage | V _{in} | −0.1 ~ VDD+0.1 | V |
| PDN input current | I _{in} | ±10 | mA |
| Output Current | Iout | ±0.5 | mA |
| Operating Temperature Range | Topr | −30 ~ +85 | °C |
| Storage Temperature Range | Tstg | −40 ~ +125 | °C |

Functional Block Diagram



■Magnetic ① and Electrical Characteristics (Ta=25°C VDD=3.0V)

| Item | Symbol | Conditions | Min. | Тур. | Max. | Unit |
|---------------------------|-------------------|---------------|----------|------|--------|------|
| Supply Voltage | VDD | | 1.6 | | 5.5 | V |
| Operating Point | B _{OP} | | | 1.8 | 4.0 | mT |
| Release Point | B _{rp} | | -4.0 | -1.8 | | mT |
| Hysteresis | Bh | | | 3.6 | | mT |
| PDN input High voltage | ۷IH | | 0.7VDD | | | V |
| PDN input Low voltage | VIL | | | | 0.3 | V |
| Output High Voltage | V _{OH} | Io=-0.5mA | VDD -0.4 | | | V |
| Output Low Voltage | V _{OL} | Io=+0.5mA | | | 0.4 | V |
| Supply Current 1*2 | IDD1 | PDN=L | | | 1 | μΑ |
| Supply Current2*2 | IDD2 | PDN=H,Average | | 60 | 150 | μΑ |
| PDN input Current | Iin | | -1 | | 1 | μΑ |
| PDN mode transition time1 | T _{PD} 1 | Active→PDN | | | (36.6) | μsec |
| PDN mode transition time2 | T _{PD} 2 | PDN→Active | | | 100 | μsec |

| Item | Symbol | Conditions | Min. | Тур. | Max. | Unit |
|-----------------------|------------------|------------|------|------|------|------|
| Pulse Drive Period | T _{PD3} | PDN=H | 0.5 | 1.0 | 1.5 | msec |
| PDN input Pluse Width | T _W | | 100 | | | μsec |
| Pulse Drive Time | T _{PD4} | PDN=H | 12.2 | 24.4 | 36.6 | μsec |

■Magnetic Characteristics ② (Ta=-30~+85°C VDD=3.0V)

| Item | Symbol | Conditions | Min. | Тур. | Max. | Unit |
|-----------------|-----------------|------------|------|------|------|------|
| Operating Point | B _{OP} | | | 1.8 | 4.2 | mT |
| Release Point | B _{rp} | | -4.2 | -1.8 | | mT |
| Hysteresis | Bh | | | 3.6 | | mT |

Note) The above specifications are design targets.

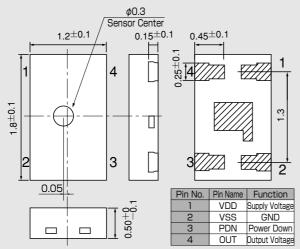
^{*1:} Positive("+") polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor (Bop,Brp)
*2: In case of PDN pin is held at VDD or VSS.
*3: This transition time is not guarantee

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●Package (Unit:mm)



Note1) The sensor center is located within the ϕ 0.3mm circle.

Note2) The tolerances of dimensions with no mentions is $\pm 0.1 \, \text{mm}$.

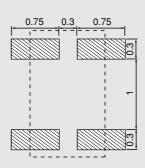
Note3) Coplanarity:The differnces between standoff of terminals are max.50 μ m.

Note4) Shaded area is plating area

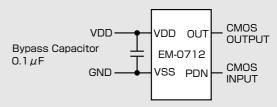
Note5) The center shadow area of the bottom of HIC does not need to be soldered.

This area shares the lead frame with VSS inside the package and please be careful not to short this area to pins except No.2.

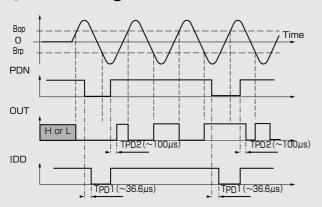
●(For reference only)Land Pattern (Unit:mm)



Application Circuit

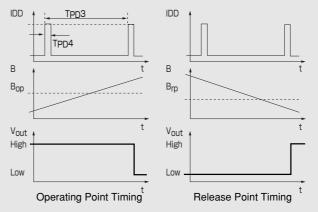


Function Timing Chart 1

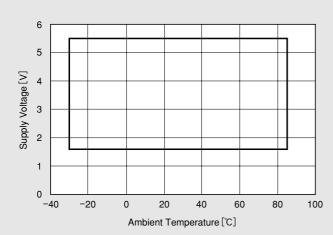


Note1) In power down mode, Output is kept current status. Note2) When VDD is supplied ,output settling time after power supply voltage exceeds 1.6V is equal to TPD2.

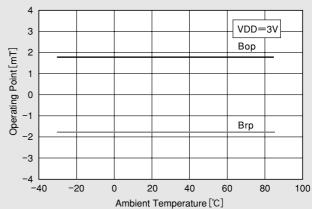
●Function Timing Chart2 (PDN=H)



Supply Voltage



Temparature Dependence of Bop. Brp



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